Absolute Maximum Ratings

Rating	Symbol	Value	Units
Peak Pulse Current (tp = 8/20µs)	I_{PP}	6	A
ESD per IEC 61000-4-2 (Contact)(1) ESD per IEC 61000-4-2 (Air)(1)	V_{ESD}	±25 ±30	kV
Operating Temperature	T_J	-40 to +125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

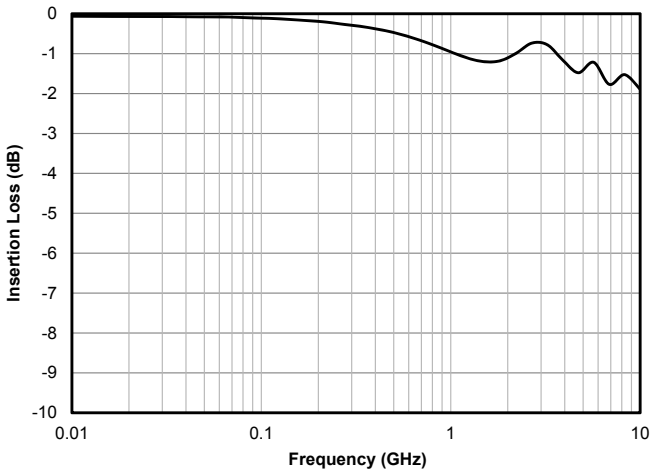
Electrical Characteristics (T=25°C unless otherwise specified)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Units
Reverse Stand-Off Voltage	V_{RWM}	-40°C to 125°C Pin 1 or Pin 2 to Pin 3				5	V
Reverse Breakdown Voltage	V_{BR}	I_t = 1mA, Pin 1 or 2 to Pin 3	-40°C to 125°C	6.5	9	11	V
Reverse Leakage Current	I_R	V_{RWM} = 5V	T = 25°C		0.005	0.100	µA
Clamping Voltage	V_C	I_{PP} = 1A, tp = 8/20µs, Pin 1 or 2 to Pin 3				12	V
Clamping Voltage	V_C	I_{PP} = 6A, tp = 8/20µs, Pin 1 or 2 to Pin 3				17	V
ESD Clamping Voltage(2)	V_C	I_{PP} = 4A, tp = 0.2/100ns (TLP) Pin 1 or 2 to Pin 3			11		V
ESD Clamping Voltage(2)	V_C	I_{PP} = 16A, tp = 0.2/100ns (TLP) Pin 1 or 2 to Pin 3			17		V
Dynamic Resistance(2), (3)	R_{DYN}	tp = 0.2/100ns (TLP) Pin 1 or 2 to Pin 3			0.50		Ohms
Total Channel Capacitance	C_{IN}	V_R = 0V, f = 1MHz Pin 1 or 2 to Pin 3	T = 25°C		0.95	1.2	pF
Differential (SDD21) Cut-Off Frequency	f_{3dB}	50 Ohm Source and Load Termination			3		GHz
Common Mode (SCC21) Attenuation	f_{ATT}	f = 75MHz			3		dB
		f = 500MHz			10		dB
		f = 1GHZ - 2.5GHz			20		dB
Channel Resistance	R_{CH}	Input to Output			1.3	1.8	Ohms

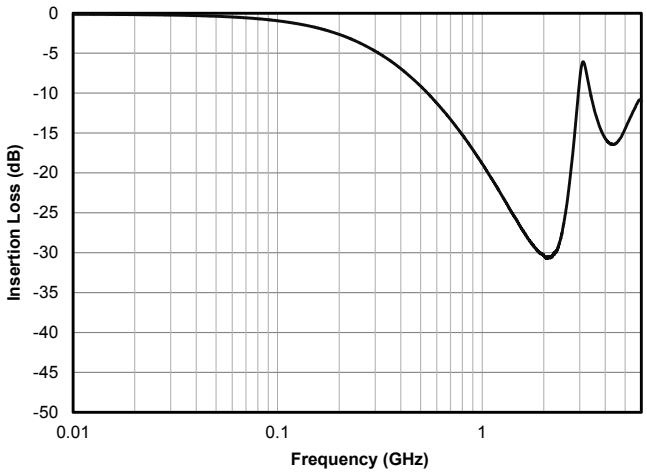
Notes:
(1): ESD Gun return path to Ground Reference Plane (GRP)
(2): Transmission Line Pulse Test (TLP) Settings: tp = 100ns, tr = 0.2ns, I_{TLP} and V_{TLP} averaging window: t_1 = 70ns to t_2 = 90ns.
(3): Dynamic resistance calculated from I_{TLP} = 4A to I_{TLP} = 16A

Typical Characteristics

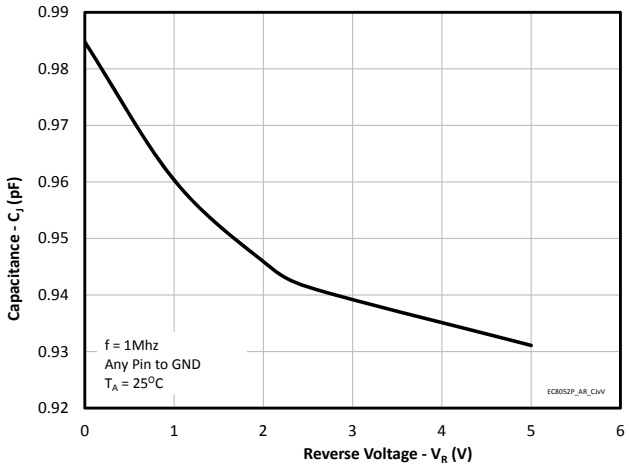
Differential Mode Attenuation vs. Frequency



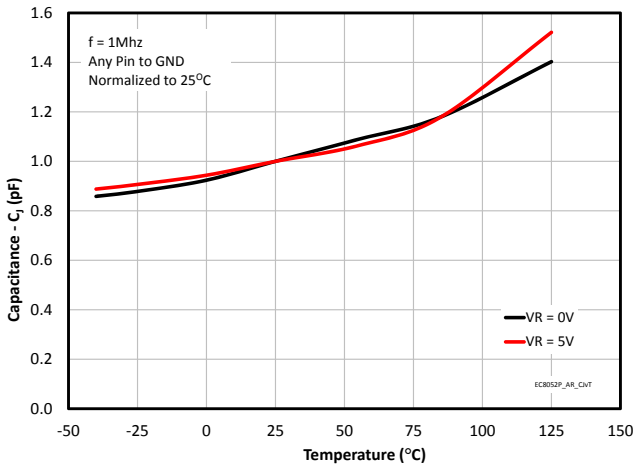
Common Mode Attenuation vs. Frequency



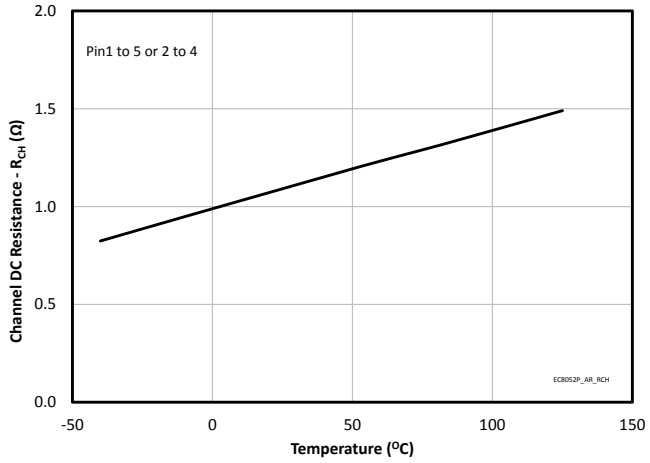
Junction Capacitance vs. Reverse Voltage



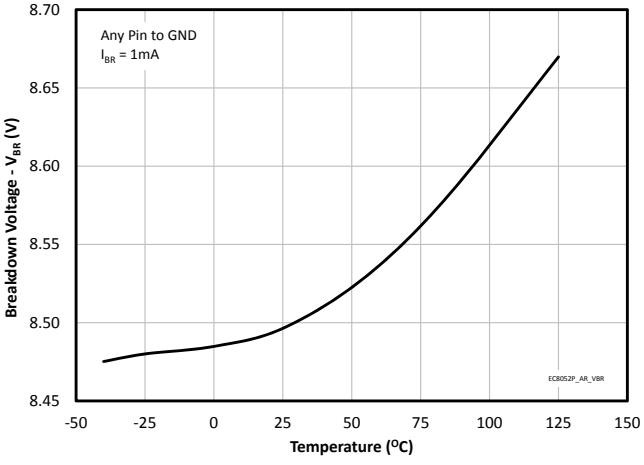
Junction Capacitance vs. Temperature



Channel DC Resistance vs. Temperature

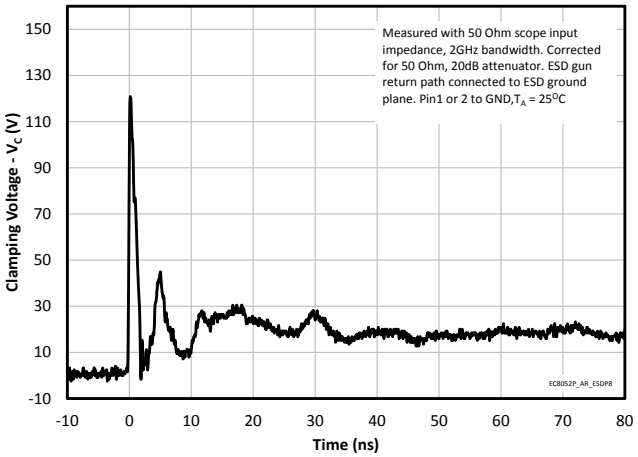


Breakdown Voltage (V_{BR}) vs. Temperature

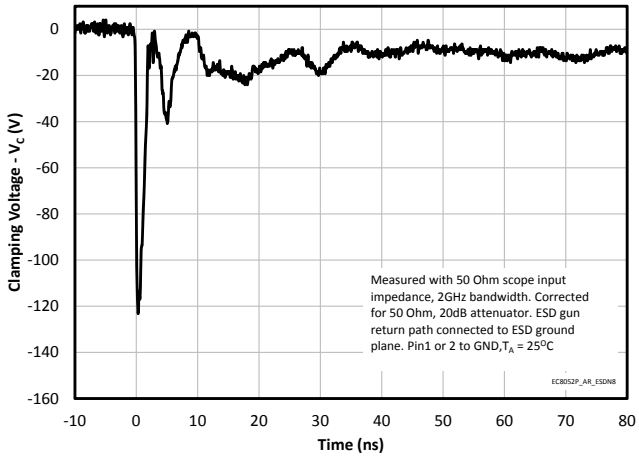


Typical Characteristics

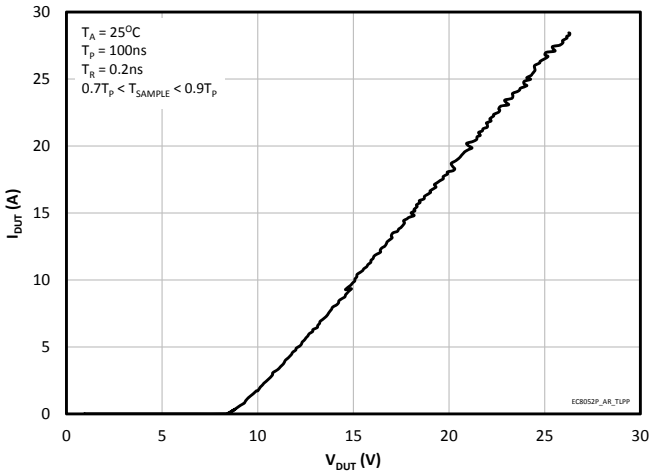
ESD Clamping (+8kV Contact per IEC 61000-4-2)



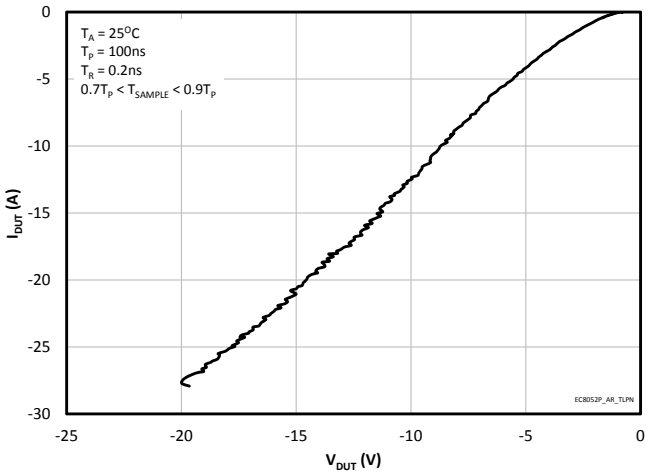
ESD Clamping (-8kV Contact per IEC 61000-4-2)



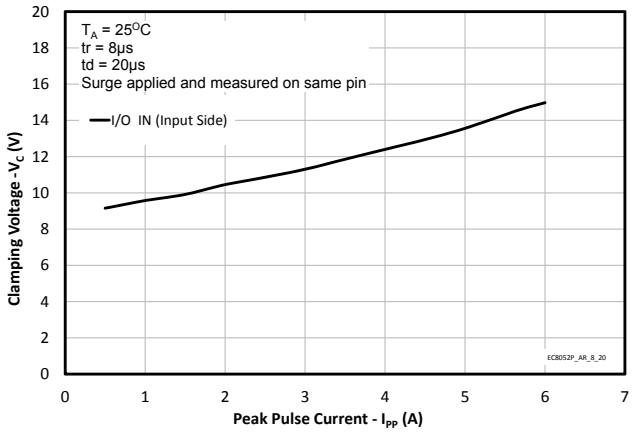
TLP Characteristic (Positive)



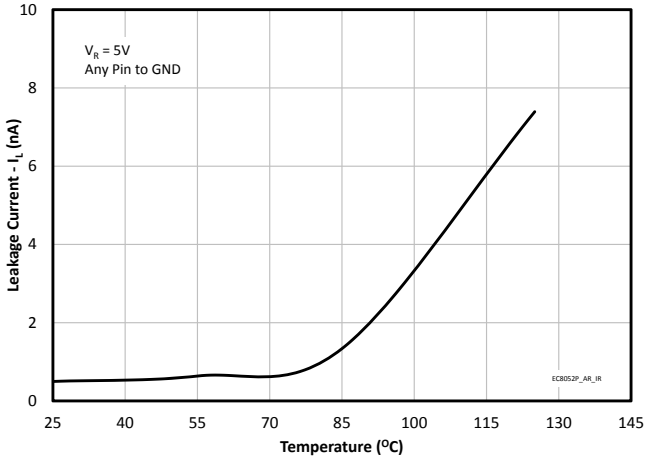
TLP Characteristic (Negative)



Clamping Voltage vs. Peak Pulse Current (tp=8/20us)



Reverse Leakage vs. Temperature



Application Information

USB Interface Protection

EClamp8052P may be used to protect D+ and D- lines against ESD and EMI in USB 2.0, USB 3.0, and USB 3.1 applications. USB D+ and D- lines enter at pins 1 and 2 (connector side) and exit at pins 4 and 5. The TVS diodes are internally connected at pins 1 and 2 and therfore must be located towards the connector on the PCB. Pin 3 is connected to the ground plane. Figures 1 is an example of protecting a USB 3.0 Type-A interface (host side shown).

For USB 3.0 applications, RClamp3324T is recommended for protecting the 5Gb/s SuperSpeed line pairs. Lines are routed through the device at pins 1-4. Traces should be kept the same length to avoid impedance mismatch. Ground is connected at pins 5 and 6. The differential impedance of each pair can be controlled for USB 3.0 (85 Ohms +/-15%) while maintaining a minimum trace-to-trace and trace-to-pad spacing. Individual PCB design constraints may necessitate different spacing or trace width. Both ground pads should be connected for optimal performance. Ground connection is made using filled via-in-pad. Additional information may be found on the device data sheet.

Single line devices such as uClamp0571P are recommended for surge and ESD protection of the VBus line. This device features high surge and ESD capability and may be used on 5V power rails.

Device Placement

Placement of the protection component is a critical element for effective ESD suppression. TVS diodes should be placed as close to the connector as possible. This helps reduce transient coupling to nearby traces. Ground connections should be made directly to the ground plane using micro-vias. This reduces parasitic inductance in the ground path and minimizes the clamping voltage seen by the protected device.

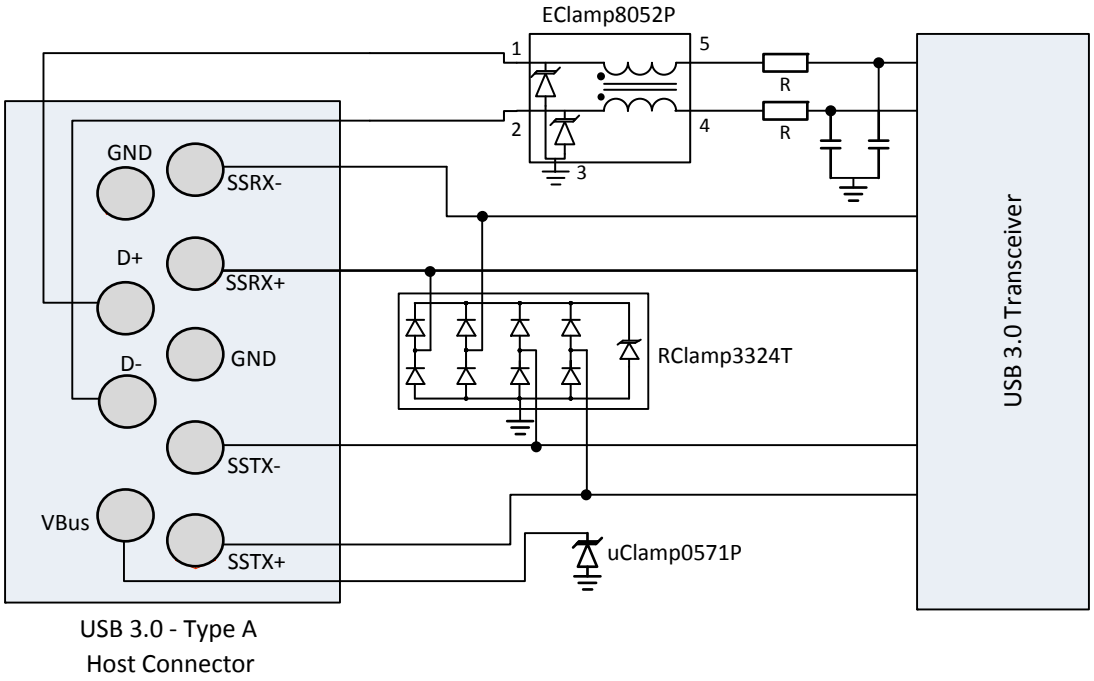


Figure 1 - USB 3.0 Type-A Protection Example

Application Information

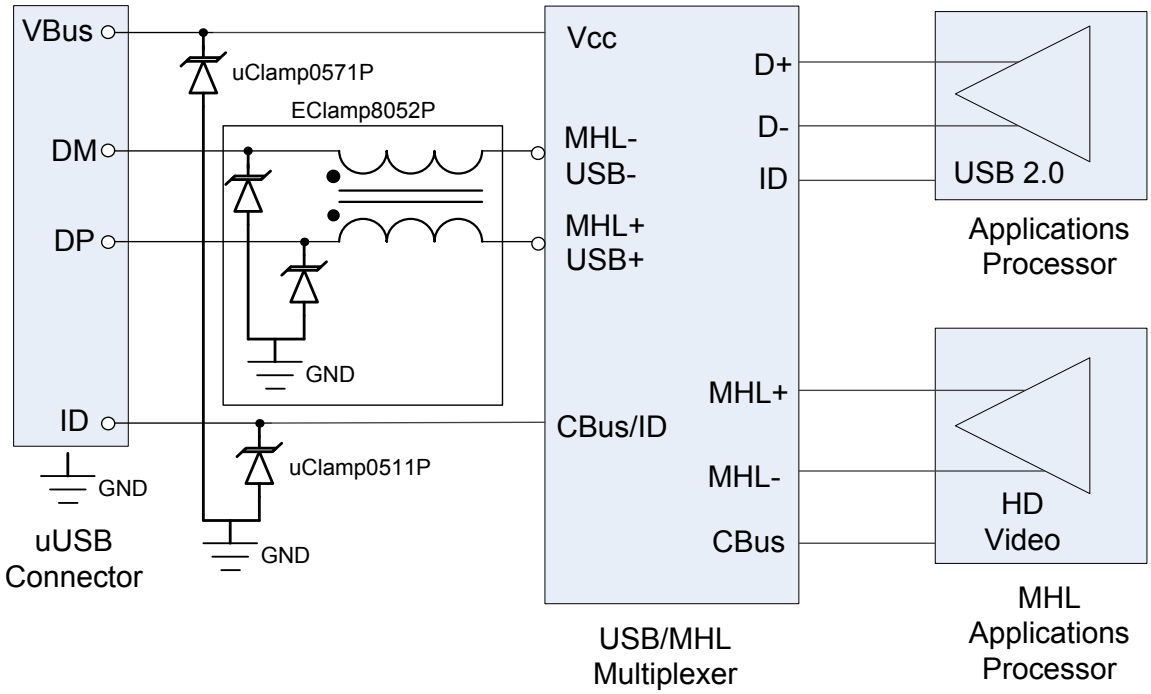


Figure 2 - USB2.0 / MHL Interface Protection

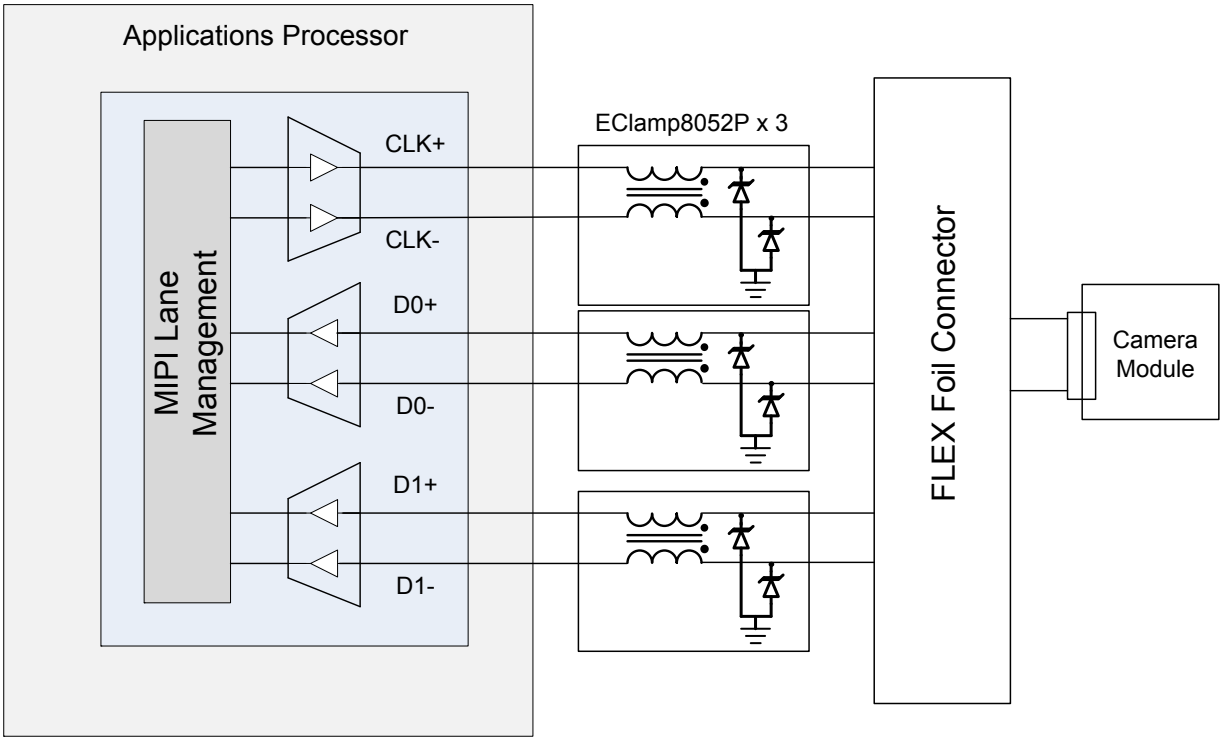
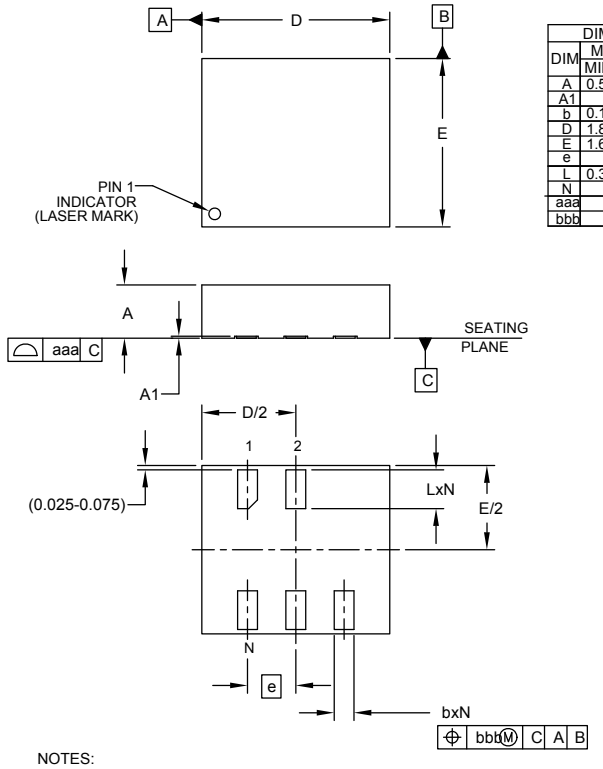


Figure 3 - MIPI Camera Serial Interface Protection

Outline Drawing - SGP1917N5

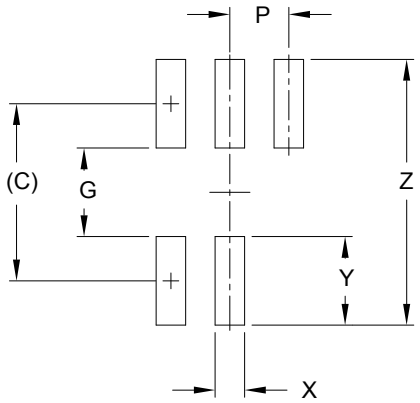


DIMENSIONS			
DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.50	0.55	0.60
A1	See Note 2		
b	0.15	0.20	0.25
D	1.85	1.90	1.95
E	1.65	1.70	1.75
e	0.50 BSC		
L	0.35	0.40	0.45
N	5		
aaa	0.08		
bbb	0.10		

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. A1 BOTTOM SOLDER MASK (0.020+/-0.007)
   SOLDER PAD (0.018+/-0.005)

Land Pattern - SGP1917N5

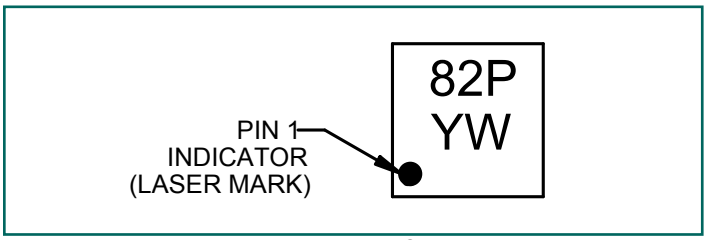


DIMENSIONS	
DIM	MILLIMETERS
C	(1.50)
G	0.75
P	0.50
X	0.25
Y	0.75
Z	2.25

NOTES:

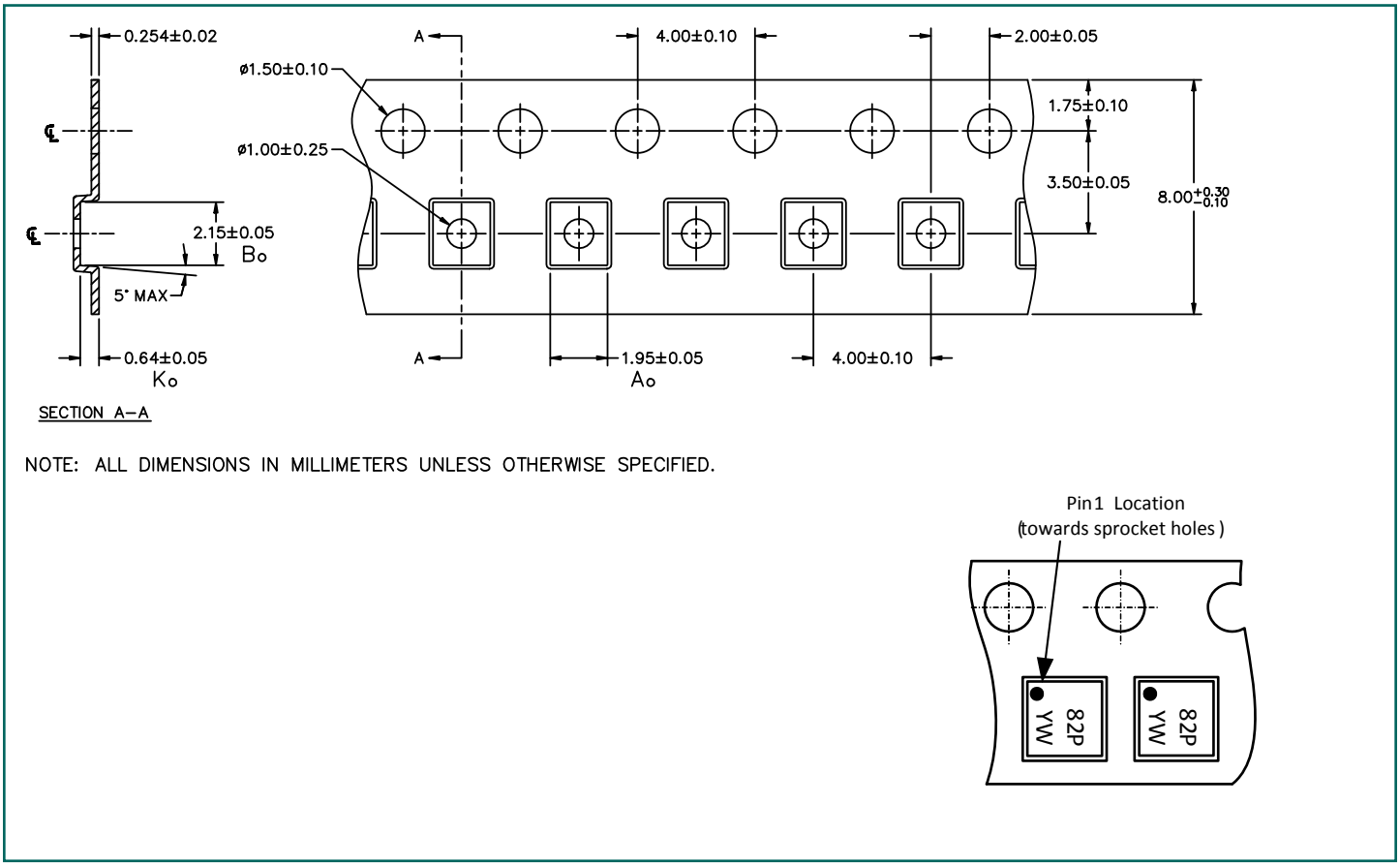
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
   CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR
   COMPANY'S MANUFACTURING GUIDELINES ARE MET.

Marking Code



YW = Alphanumeric character Date Code

Tape and Reel Specification - Plastic Tape, 4mm Pitch



Ordering Information

Part Number	Qty per Reel	Reel Size	Carrier Tape	Pitch
EClamp8052P.TCT	3000	7 Inch	Plastic	4mm
EMIClamp and EClamp are trademarks of Semtech Corporation.				

Contact Information

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